







9.0 x 7.0 x 2.24 mm

> OVERVIEW:

ASGTX temperature compensated Crystal Oscillators are designed to accommodate a broad breadth of Precision TCXO requirements, without NRE and extended lead-times. This oscillator series is designed and manufactured by Abracon Corporation and is available to order from 1pc to high volume production quantities.

 1-5 day quick-turn availability of a TCXO/VCTCXO with LVCMOS output, <u>Any frequency</u> between 10MHz & 250MHz

For example, if a reference oscillator requirement calls out 49.7521 MHz; $\pm 1.00 \text{ ppm TCXO/VCTCXO}$ with **LVCMOS** output, ASGTX can be configured and shipped within 1-5 days and in most cases, same day if order is received before noon. Customers with low-to-mid annual volume requirements find it difficult to procure custom frequency TCXO/VCTXCO's without costly NRE charges and/or long lead-times ($\geq 12 \text{ weeks}$).

• 1-5 day quick turn availability of a TCXO/VCTXCO requiring LVDS or LVPECL Differential output, Any frequency between 10MHz to 1.50GHz

ASGTX is available with either **LVDS** or **LVPECL** output, from **10MHz** to **1.50GHz**; at any desired frequency, such as 149.875MHz, 1.00GHz, 1.5GHz, etc. with as tight as ± 1.00 ppm stability over temperature. No other solution in the marketplace currently offers such capability, especially in a small form-factor of 9.0x7.0x2.24 mm.

ASGTX is suitable for a wide variety of precision timing applications where TCXO/VCTXO's are typically employed. In addition, for high frequency LO requirements, traditionally customers have relied on SAW based oscillators. Such devices are only available at a few fixed frequencies, such as 915MHz, 1.0GHz, etc. They are typically in 9x14mm or bigger packages and vary as much as ± 100 ppm over temperature.

Although ASGTX series will be slightly less favorable in phase noise performance compared to SAW based oscillators, it offers the following key advantages:

- o ± 1.00 ppm stability over -30°C to +70°C & ± 2.00 ppm stability over -40°C to +85°C
- o Any carrier frequency between 10MHz & 1.50GHz
- o LVCMOS Output (10MHz to 250MHz) or LVDS / LVPECL Output (10MHz to 1.50GHz)
- o Small form-factor of 9.0x7.0x2.24 mm
- o No NRE or lead-time

> FEATURES:

- 10MHz to 1.50GHz, any Carrier Frequency in differential mode (LVDS or LVPECL)
- 10MHz to 250MHz, any Carrier Frequency in LVCMOS mode
- -40°C to +85°C operating temperature range
- ±1.0ppm stability over -30°C to +70°C and ±2.0ppm stability over -40°C to +85°C
- Minimum guaranteed pull ability of \pm 10ppm in VCTCXO mode
- Good Phase Noise, excellent Harmonics and Spurious content
- Guaranteed rms jitter of 1.80ps maximum @ 1.50GHz carrier (LVDS mode)
- Immediate availability, 5-day maximum lead-time for small quantities

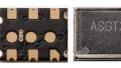
► APPLICATIONS:

- 40G & 100G Ethernet
- WiMax,
- LTE, BTS
- CATV, LAN, LMDS
- Point-to-Point communication networks









9.0 x 7.0 x 2.24 mm

KEY ELECTRICAL SPECIFICATIONS:

Para	meters	Minimum	Typical	Maximum	Units	Notes
	LVCMOS	10		250		
Frequency:	LVDS	10		1500	MHz	
	LVPECL	10		1500	1	
Operating Tempera	iture:	-40		+85	°C	
Storage Temperatu	re:	-40		+85	°C	
Frequency Stability	<i>i</i> :		_			
Initial Set Tole	rance	-1.50	≤±1.00	+1.50	ppm	1 hour after reflow
Stability over	-30°C to +70°C	-1.00		+1.00	ppm	Option "1"
operating temperature*	-40°C to +85°C **	-2.00		+2.00		Option "2"
Aging @ 25°C	after one year	-1.00		+1.00	ppm	
Supply Voltage (Vo	dd):	3.135	3.300	3.465	V	
Startup Time:				3	ms	
Control Voltage***:		0		Vdd	V	In VCTCXO Mode
Frequency Pull:		±10			ppm	in verexo mode
Phase jitter RMS [(12kHz to 20MHz)			<1.00	1.80	ps	Frequency dependent

Notes

- * Relative to measured frequency post reflow
- ** Please contact Abracon for ±1.00 ppm frequency stability over -40°C to +85°C
- *** Center Control Voltage value is either $1.28V \pm 0.20V$ or, $1.55V \pm 0.20V$ for the device to be with-in ± 1.50 ppm of final frequency, 1-hour post reflow
- **** 1.8ps max is guaranteed for LVCMOS and LVDS output modes. For LVPECL mode at carrier frequency greater than 1.289GHz, the maximum RMS jitter is 3.0ps

Key Electrical Specifications – LVCMOS

Parameters		Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd}):				45	mA	Frequency dependent
Output Load:				15	pF	
Output Logic Loyal:	V_{OH}	$0.9*V_{dd}$			V	
Output Logic Level:	V_{OL}			$0.1*V_{dd}$	V	
Rise Time (Tr):				1000	ps	
Fall Time (Tf):				1000	ps	
Duty Cycle:		45		55	%	@1/2Vdd









9.0 x 7.0 x 2.24 mm

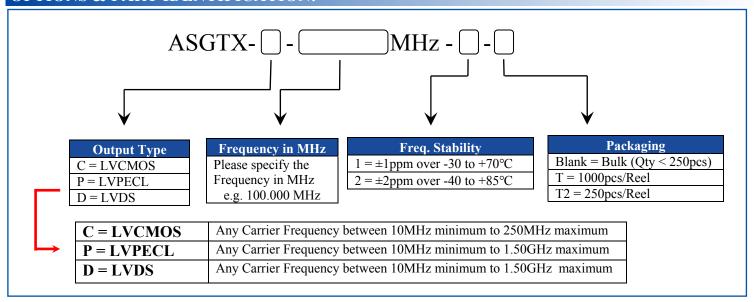
Key Electrical Specifications – LVPECL

Parameters		Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd})				60	mA	With typical LVPECL output termination
Output Logic Lovel	V_{OH}	V_{dd} -1.03		V_{dd} -0.60	V	
Output Logic Level	V_{OL}	V_{dd} -1.85		V_{dd} -1.60	V	
Rise Time (Tr):				350	ps	
Fall Time (Tf):				350	ps	
Differential Duty Cycle:		45		55	%	$DODC_{LVPECL}$

Key Electrical Specifications – LVDS

Parameters	Minimum	Typical	Maximum	Units	Notes
Supply Current (I _{dd})			40	mA	With typical LVDS output termination
Differential Output Voltage (V _{OD})	175	350		mV	
V_{OD} Magnitude Change (ΔV_{OD})			50	mV	
Offset Voltage (Vos)		1.25		V	
V_{OS} Magnitude Change (ΔV_{OS})			50	mV	
Rise Time (Tr):			350	ps	
Fall Time (Tf):			450	ps	
Differential Duty Cycle:	45		55	%	ODC_{LVDS}

○ OPTIONS & PART IDENTIFICATION:







-170.0 -180.0





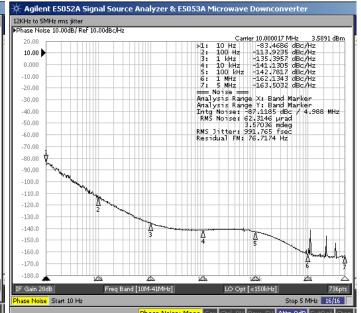
9.0 x 7.0 x 2.24 mm

TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

With LVCMOS Output; 10MHz Carrier

Agilent E5052A Signal Source Analyzer & E5053A Microwaye Do Carrier 10.000017 MHz 11.4940 dBr z -85.1847 dBg,/Hz Hz -113.2501 dBg,/Hz z -135.2830 dBg,/Hz Hz -140.9001 dBg,/Hz kHz -142.5204 dBg,/Hz z -162.3088 dBg,/Hz Camier 10.000017 MHz 11.4940 dBm 11: 10 Hz -85.1847 dBc/Hz 21: 100 Hz -113.2501 dBc/Hz 31: 1 kHz -135.2830 dBc/Hz 31: 1 kHz -135.2830 dBc/Hz 51: 100 kHz -142.5204 dBc/Hz 51: 100 kHz -142.5204 dBc/Hz 71: 5 MHz -166.7922 dBc/Hz 71: 5 MHz -166.7922 dBc/Hz Mnalysis Range X: Band Marker Analysis Range X: Band Marker Analysis Range Y: Band Marker Intg Noiset -87.8983 dBc / 4.998 MHz RMS Noiset -87.8983 dBc / 4.998 MHz RMS Noiset -87.8983 dBc / 4.998 MHz RMS Noiset -87.8983 dBc Residual FM: 52.2806 Hz 10.00 0.000 -10.00 -20.00 -30.00 -40,00 -50.00 -60.00 -70,00 -80.00 -90.00 -110.0 -120.0 -130.0 -140.0 -150.0 -160.0

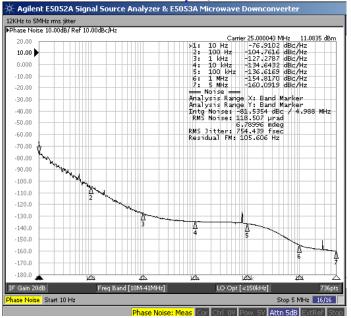
With LVDS Output; 10MHz Carrier



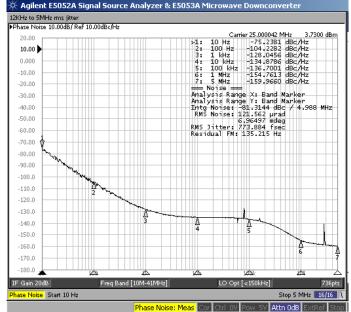
With LVCMOS Output; 25MHz Carrier

Stop 5 MHz 16/16

V Attn 5dB ExtRef St



With LVDS Output; 25MHz Carrier



ABRACON IS ISO9001:2008 CERTIFIED





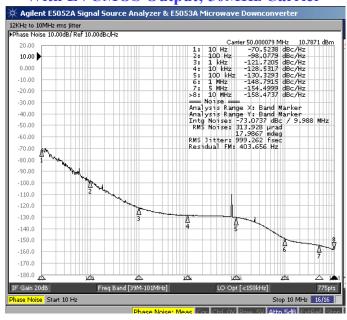




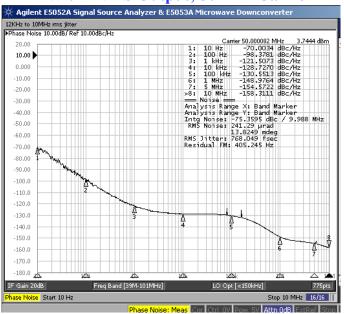
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TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

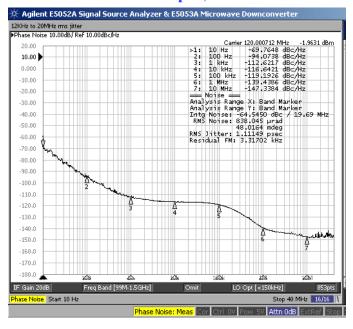
With LVCMOS Output; 50MHz Carrier



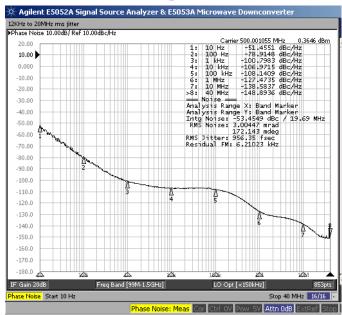
With LVDS Output; 50MHz Carrier



With LVCMOS Output; 120MHz Carrier



With LVPECL Output; 500MHz Carrier



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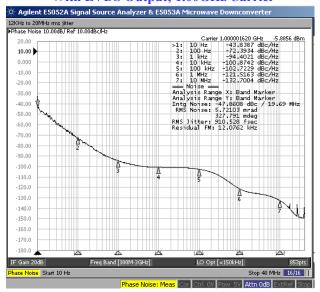




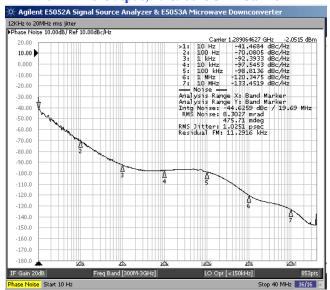
9.0 x 7.0 x 2.24 mm

TYPICAL PHASE NOISE & JITTER CHARACTERISTICS

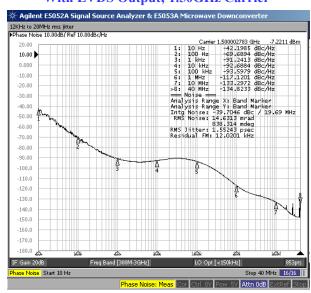
With LVDS Output; 1.00GHz Carrier



With LVDS Output; 1.2890625GHz Carrier



With LVDS Output; 1.50GHz Carrier

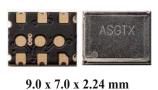


Carrier	RF Output	rms Phase Jitter	Integration Bandwidth
10.00MHz	LVDS	992 fs	12kHz to 5MHz
25.00MHz	LVDS	774 fs	12kHz to 5MHz
50.00MHz	LVDS	768 fs	12kHz to 10MHz
120.00MHz	LVCMOS	1.1 ps	12kHz to 20MHz
500.00MHz	LVPECL	956 fs	12kHz to 20MHz
1.00GHz	LVDS	911 fs	12kHz to 20MHz
1.2890625GHz	LVDS	1.03 ps	12kHz to 20MHz
1.50GHz	LVDS	1.55 ps	12kHz to 20MHz

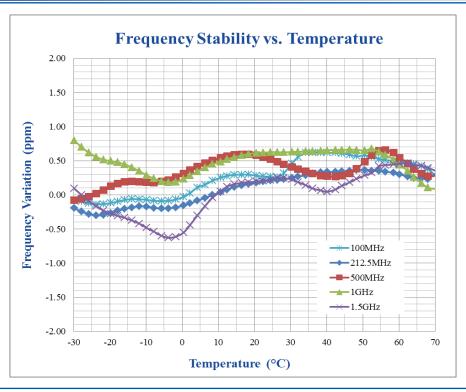




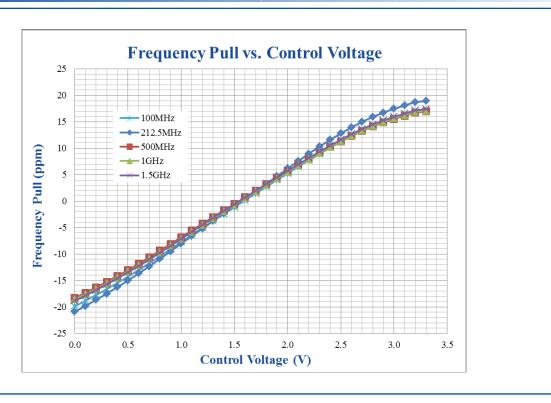




> FREQUENCY STABILITY VS. TEMPERATURE



FREQUENCY PULL VS. CONTROL VOLTAGE (VCTCXO MODE)









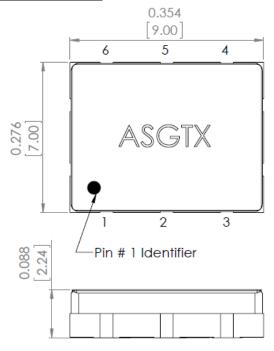




9.0 x 7.0 x 2.24 mm

OUTLINE DIMENSION:

LVCMOS output

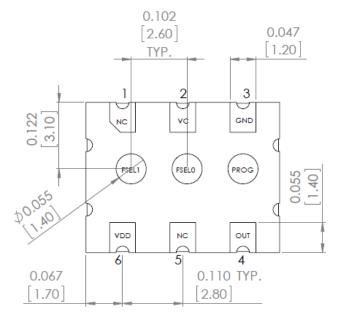


Pin #	Pin Description				
PIII#	TCXO	VCTCXO			
1	N/C (1)				
2	By-Pass (2)	Vc (3)			
3	GND				
4	RF Output				
5	N/C (1)				
6	Vdd				

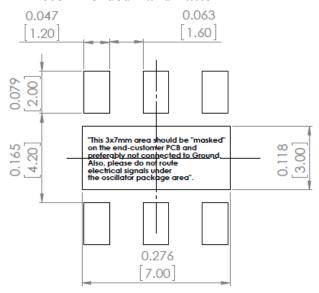
N/C ⁽¹⁾ = Please leave these pins electrically floating on the end-PCB

By-Pass ⁽²⁾ = In TCXO configuration, it is recommended that a 1,000pF COG by-pass capacitor is connected between Pin#2 and GND

 $Vc^{(3)}$ = Please connect external voltage to pull the oscillator frequency



Recommended Land Pattern



Dimensions: inches [mm]





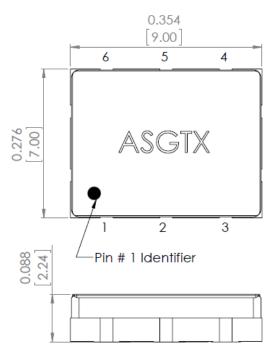


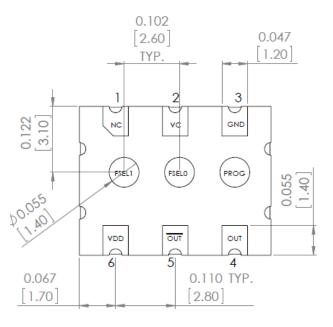




9.0 x 7.0 x 2.24 mm

LVDS/LVPECL output





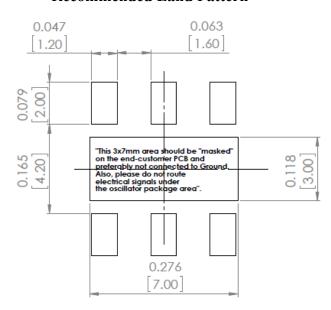
Pin #	Pin Description					
PIII #	TCXO	VCTCXO				
1	N/C (1)					
2	By-Pass (2) Vc (3)					
3	GND					
4	RF Output					
5	Complimentary RF Output					
6	Vdd					

N/C ⁽¹⁾ = Please leave this pin electrically floating on the end-PCB

By-Pass ⁽²⁾ = In TCXO configuration, it is recommended that a 1,000pF COG by-pass capacitor is connected between Pin#2 and GND

 $\mathbf{Vc}^{(3)}$ = Please connect external voltage to pull the oscillator frequency

Recommended Land Pattern



Dimensions: inches [mm]





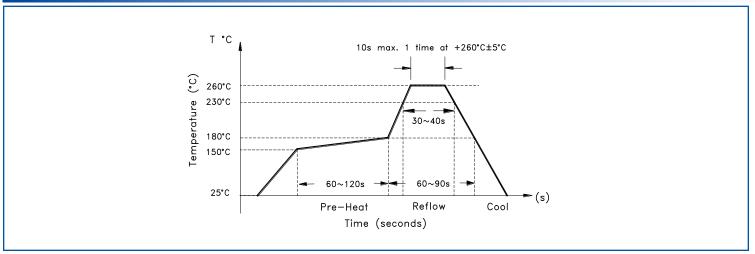




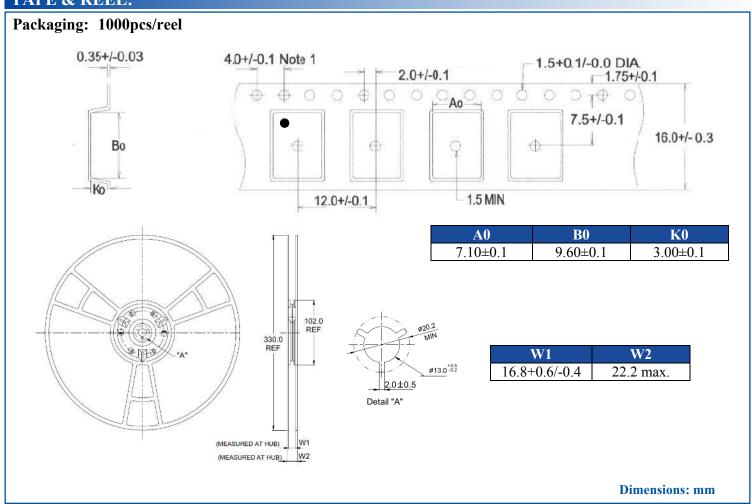


9.0 x 7.0 x 2.24 mm

REFLOW PROFILE:



► TAPE & REEL:



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